

### IGBT MODULE (S series) 1200V / 50A / PIM



#### ■ Features

- Low  $V_{CE(sat)}$
- Compact package
- P.C. board mount
- Converter diode bridge, Dynamic brake circuit

#### ■ Applications

- Inverter for motor drive
- AC and DC servo drive amplifier
- Uninterruptible power supply

#### ■ Maximum ratings and characteristics

● Absolute maximum ratings ( $T_c=25^\circ\text{C}$  unless without specified)

Item	Symbol	Condition	Rating	Unit		
Inverter	Collector-Emitter voltage	$V_{CES}$	1200	V		
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V		
	Collector current	$I_C$	Continuous	$T_c=25^\circ\text{C}$	75	A
				$T_c=80^\circ\text{C}$	50	
		$I_{CP}$	1ms	$T_c=25^\circ\text{C}$	150	A
				$T_c=80^\circ\text{C}$	100	
	$-I_C$		50	A		
Collector power dissipation	$P_C$	1 device	360	W		
Brake	Collector-Emitter voltage	$V_{CES}$	1200	V		
	Gate-Emitter voltage	$V_{GES}$	$\pm 20$	V		
	Collector current	$I_C$	Continuous	$T_c=25^\circ\text{C}$	35	A
				$T_c=80^\circ\text{C}$	25	
		$I_{CP}$	1ms	$T_c=25^\circ\text{C}$	70	A
				$T_c=80^\circ\text{C}$	50	
Collector power dissipation	$P_C$	1 device	180	W		
Repetitive peak reverse voltage	$V_{RRM}$		1200	V		
Converter	Repetitive peak reverse voltage	$V_{RRM}$	1600	V		
	Average output current	$I_O$	50Hz/60Hz sine wave	50	A	
	Surge current (Non-Repetitive)	$I_{FSM}$	$T_j=150^\circ\text{C}$ , 10ms	520	A	
	$I^2t$ (Non-Repetitive)	$I^2t$	half sine wave	1352	$\text{A}^2\text{s}$	
Operating junction temperature	$T_j$		+150	$^\circ\text{C}$		
Storage temperature	$T_{stg}$		-40 to +125	$^\circ\text{C}$		
Isolation voltage	between terminal and copper base *2	$V_{iso}$	AC : 1 minute	AC 2500	V	
	between thermistor and others *3			AC 2500		
Mounting screw torque			3.5 *1	N·m		

\*1 Recommendable value : 2.5 to 3.5 N·m (M5)

\*2 All terminals should be connected together when isolation test will be done.

\*3 Terminal 8 and 9 should be connected together. Terminal 1 to 7 and 10 to 24 should be connected together and shorted to copper base.

● Electrical characteristics (Tj=25°C unless otherwise specified)

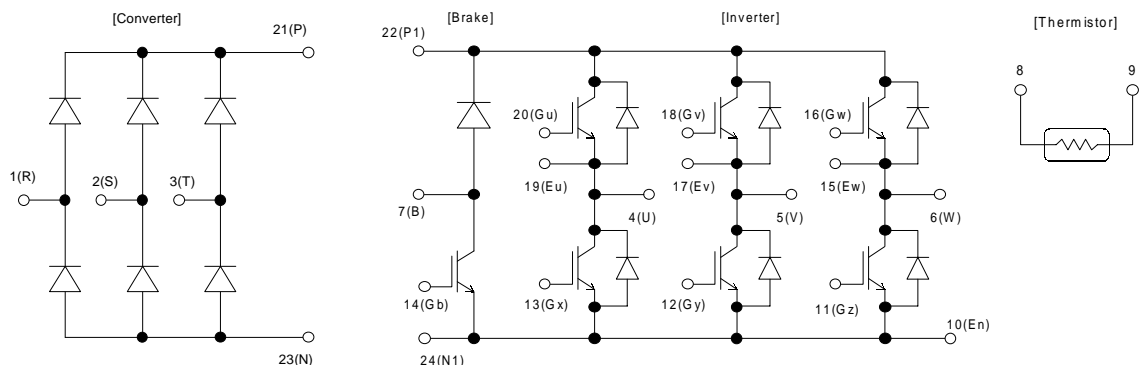
Item	Symbol	Condition	Characteristics			Unit			
			Min.	Typ.	Max.				
Inverter	Zero gate voltage collector current	ICES	VCE=1200V, VGE=0V			1.0	mA		
	Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20V			0.2	µA		
	Gate-Emitter threshold voltage	VGE(th)	VCE=20V, Ic=50mA			5.5	7.2	8.5	V
	Collector-Emitter saturation voltage	VCE(sat)	VGE=15V, Ic=50A	chip	2.1		V		
				terminal	2.3	2.7			
	Input capacitance	Cies	VGE=0V, VCE=10V, f=1MHz			6000		pF	
	Turn-on time	ton	VCC=600V			0.35	1.2	µs	
		tr	Ic=50A			0.25	0.6		
		tr(i)	VGE=±15V			0.1			
	Turn-off	toff	RG=24Ω			0.45	1.0		
tf					0.08	0.3			
Forward on voltage	VF	IF=50A	chip	2.3		V			
			terminal	2.5	3.3				
Reverse recovery time of FRD	trr	IF=50A				0.35	µs		
Brake	Zero gate voltage collector current	ICES	VCEs=1200V, VGE=0V			1.0	mA		
	Gate-Emitter leakage current	IGES	VCE=0V, VGE=±20V			0.2	µA		
	Collector-Emitter saturation voltage	VCE(sat)	Ic=25A, VGE=15V	chip	2.1		V		
				terminal	2.25	2.7			
	Turn-on time	ton	VCC=600V			0.35	1.2	µs	
		tr	Ic=25A			0.25	0.6		
	Turn-off time	toff	VGE=±15V			0.45	1.0		
		tf	RG=51Ω			0.08	0.3		
	Reverse current	Irrm	VR=1200V				1.0	mA	
	Forward on voltage	VFM	IF=50A	chip	1.1		V		
terminal				1.2	1.5				
Reverse current	Irrm	VR=1600V				1.0	mA		
Thermistor	Resistance	R	T=25°C			5000		Ω	
			T=100°C			465	495		520
	B value	B	T=25/50°C			3305	3375	3450	K

● Thermal resistance Characteristics

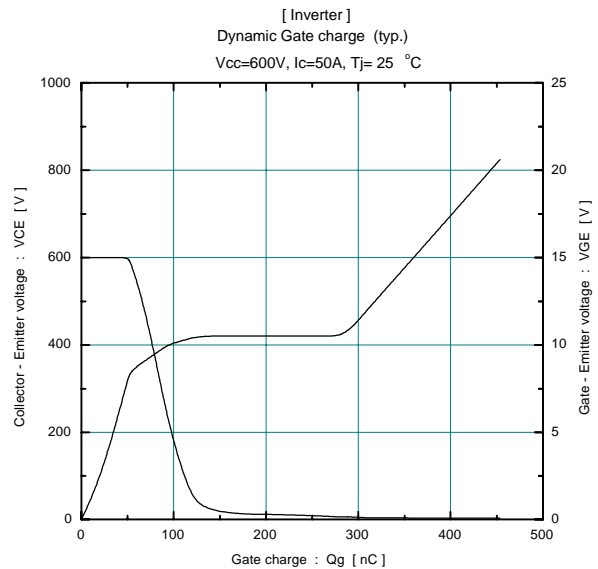
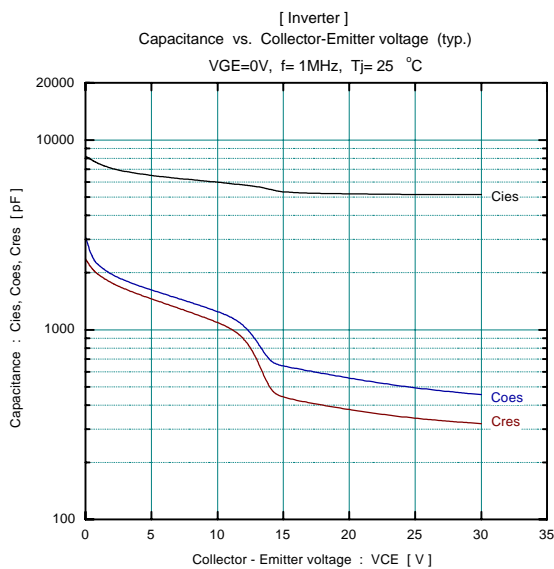
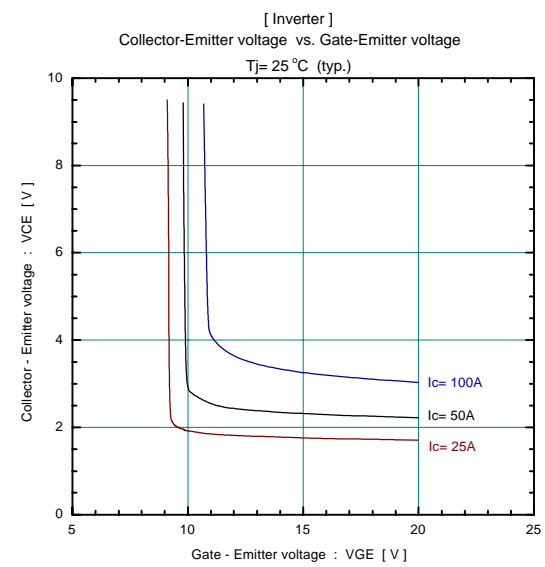
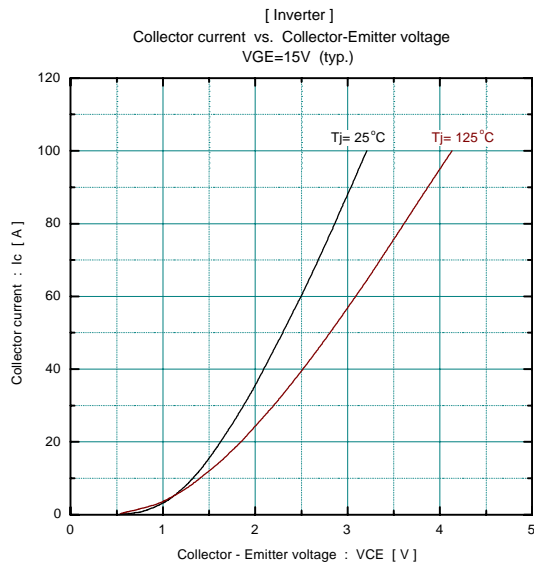
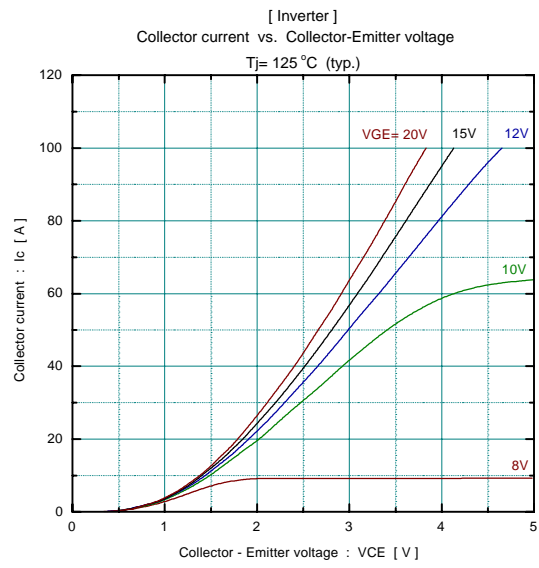
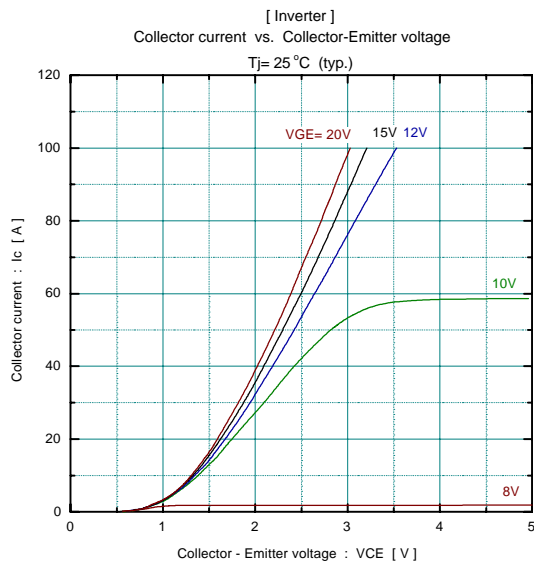
Item	Symbol	Condition	Characteristics			Unit
			Min.	Typ.	Max.	
Thermal resistance ( 1 device )	Rth(j-c)	Inverter IGBT			0.35	°C/W
		Inverter FWD			0.75	
		Brake IGBT			0.69	
		Converter Diode			0.50	
Contact thermal resistance *	Rth(c-f)	With thermal compound		0.05		

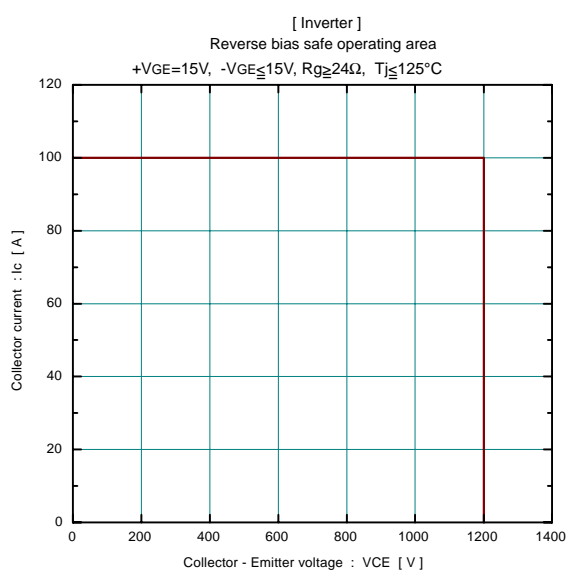
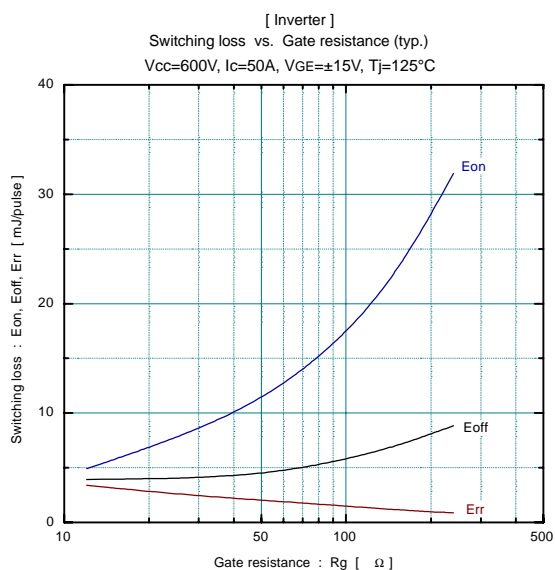
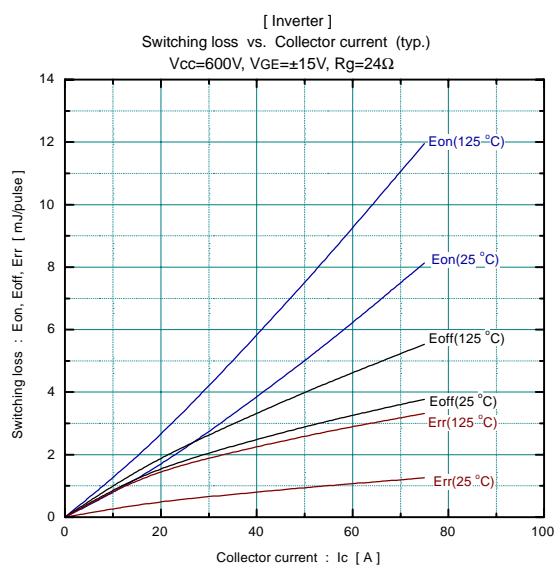
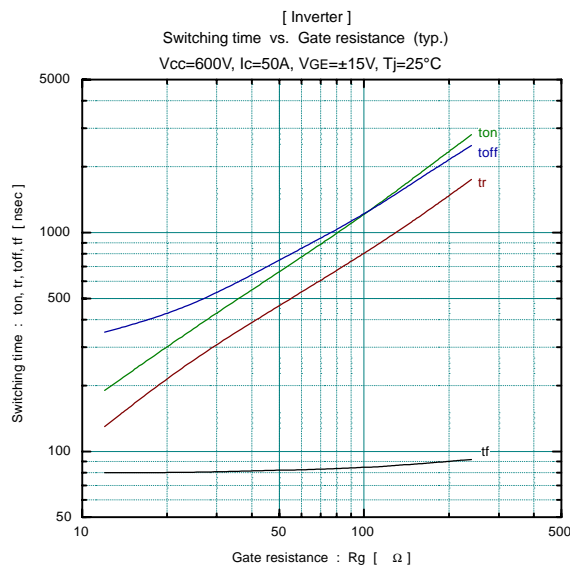
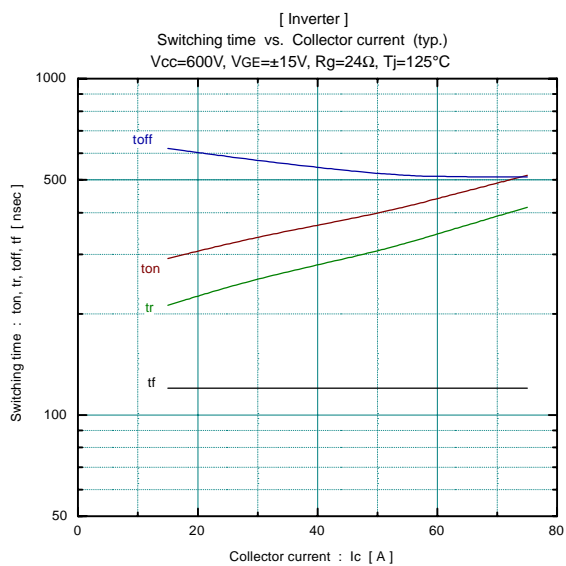
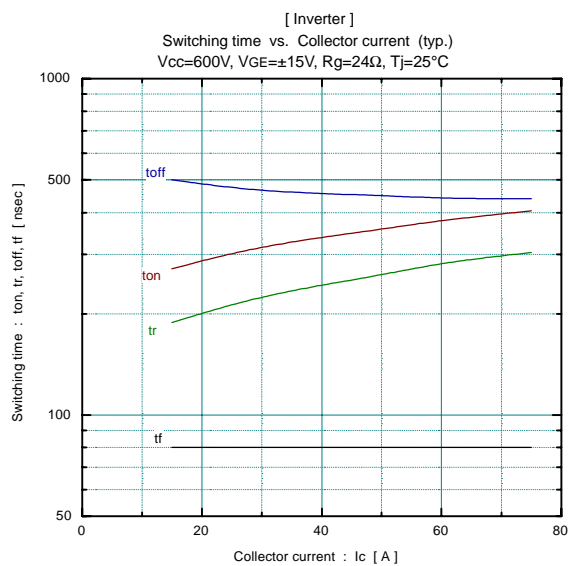
\* This is the value which is defined mounting on the additional cooling fin with thermal compound

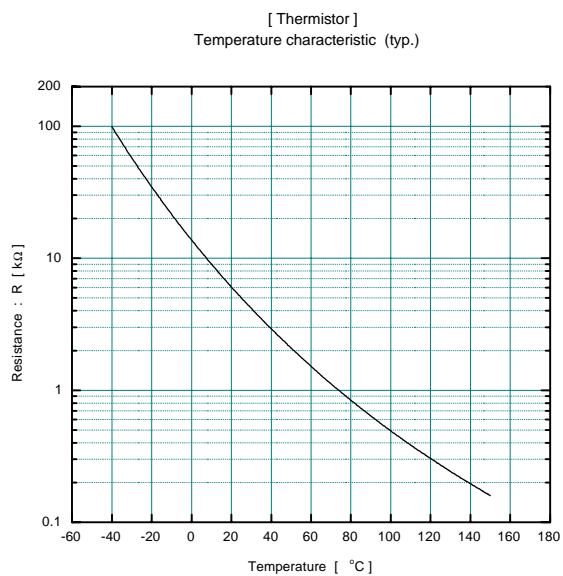
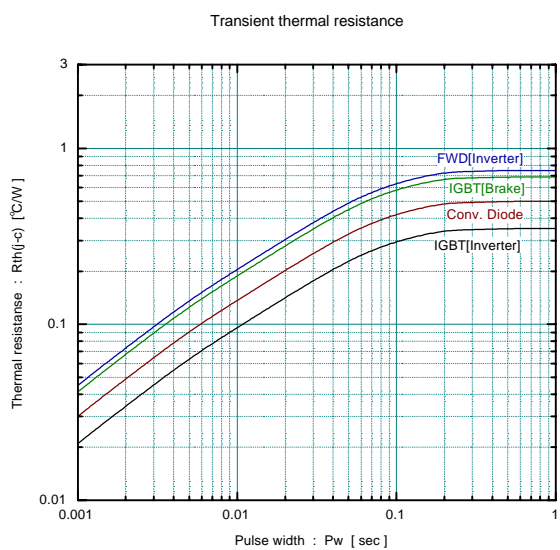
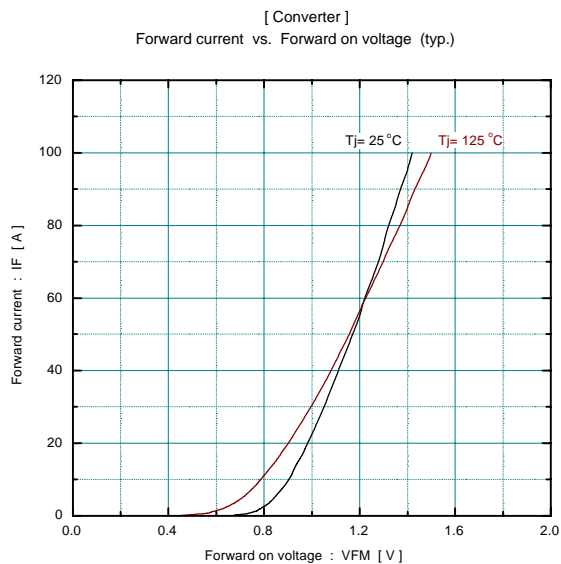
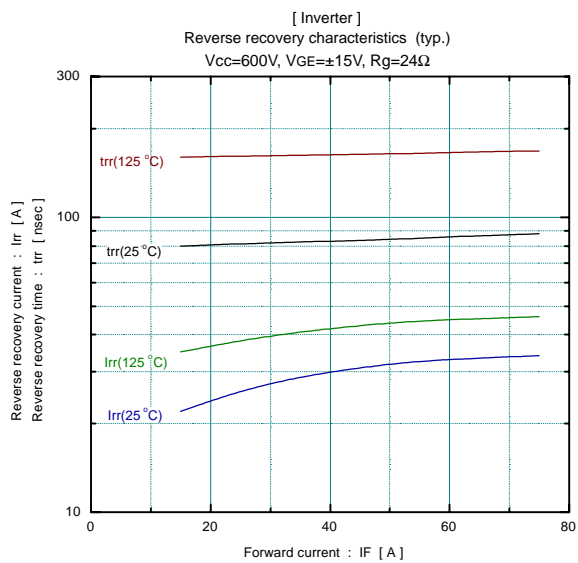
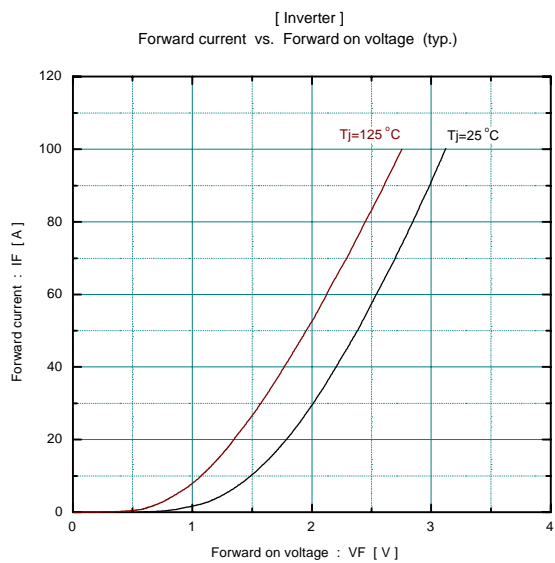
■ Equivalent Circuit Schematic

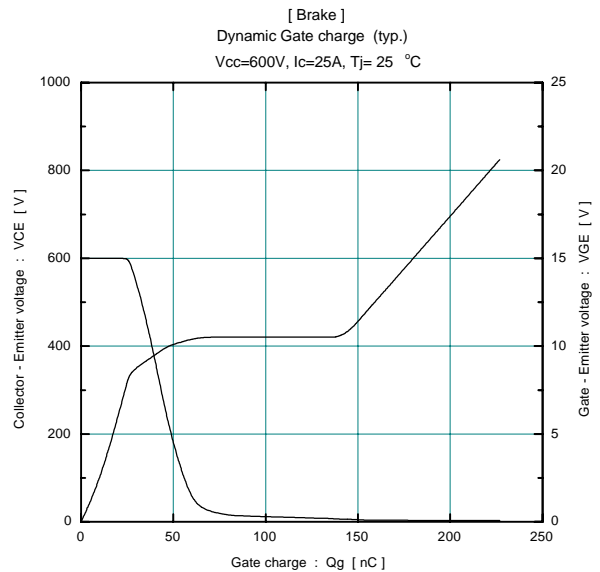
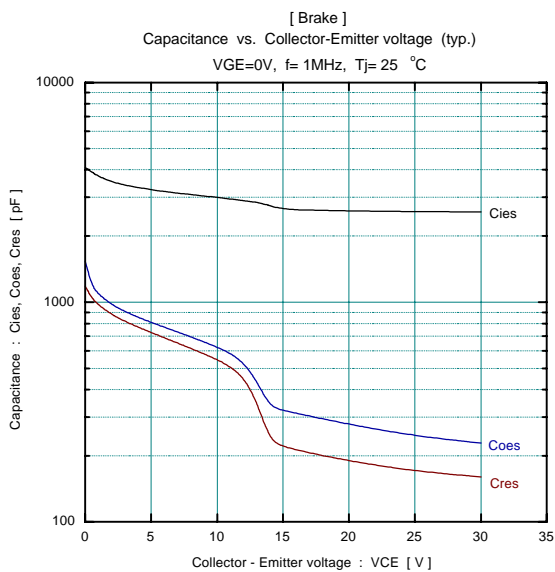
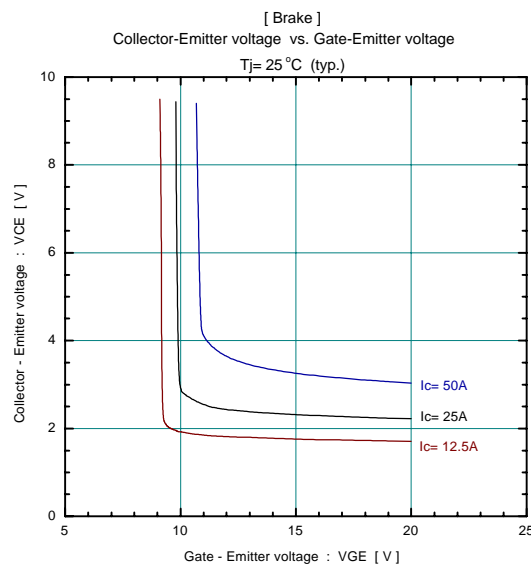
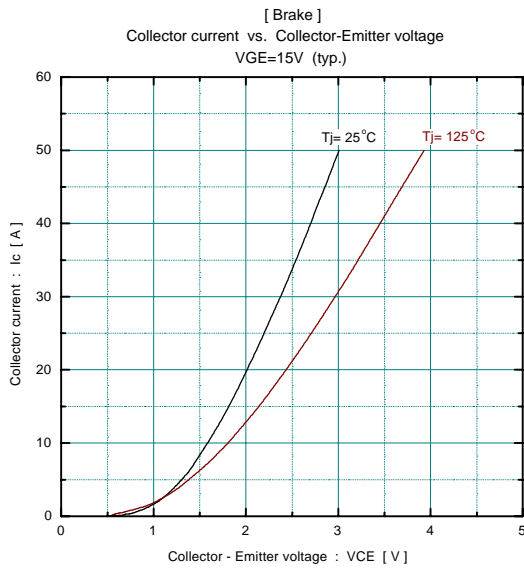
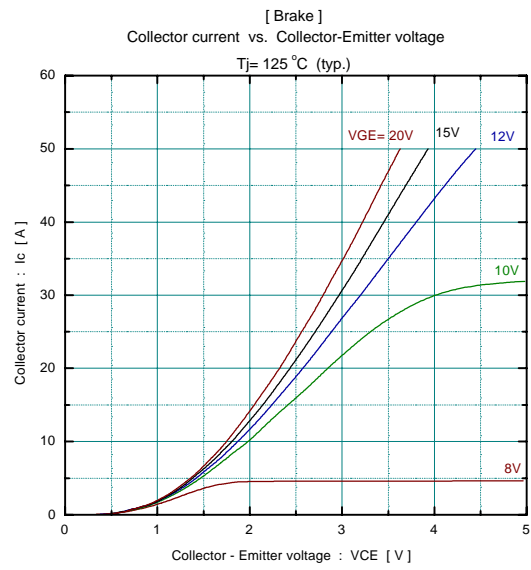
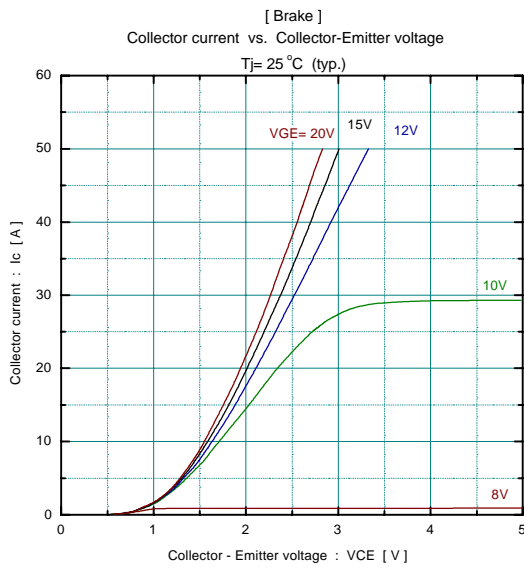


## Characteristics (Representative)

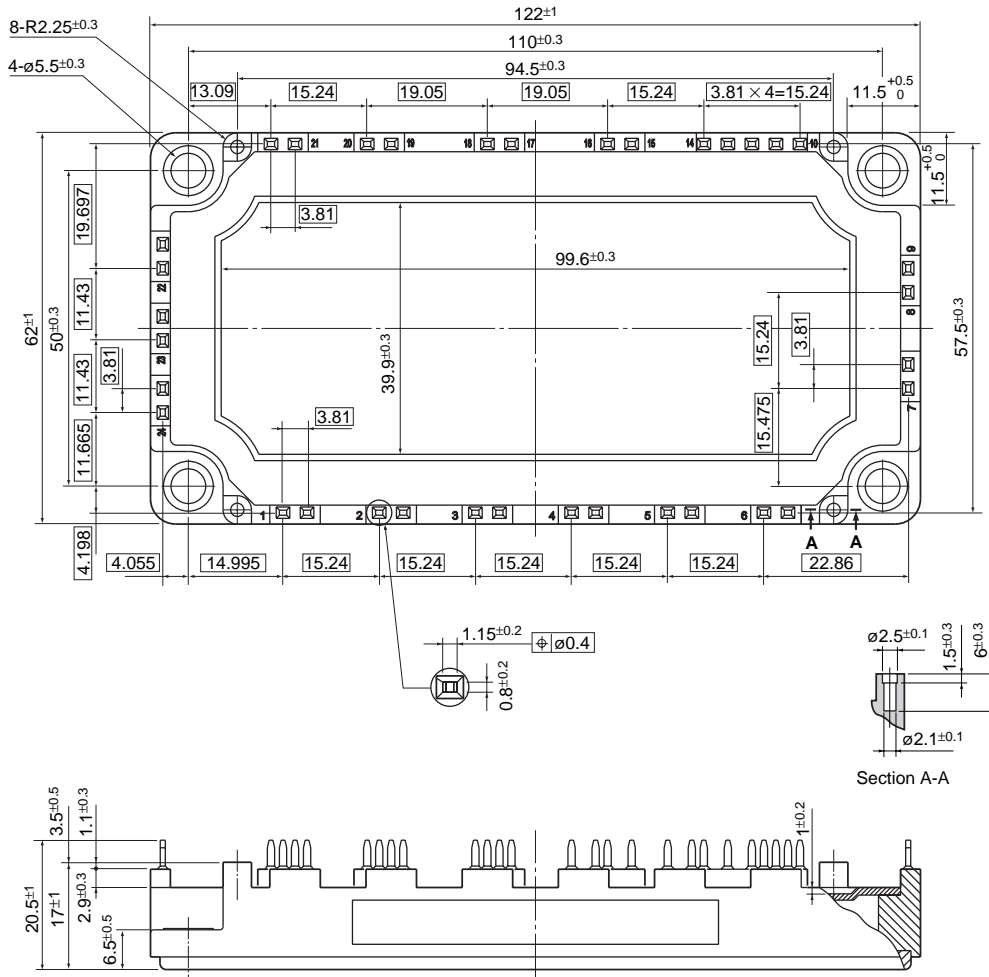








■ Outline Drawings, mm



Section A-A

□ Shows theory dimensions